





70V PNP LOW SATURATION TRANSISTOR

Features and Benefits

- BV_{CEO} > -70V
- I_C = -2.5A Continuous Collector Current
- Low Saturation Voltage (-220mV max @ -1A)
- $R_{SAT} = 117 \text{ m}\Omega$ for a low equivalent On-Resistance
- hFE specified up to -3A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- R_{BJA} efficient, 60% lower than SOT23
- 4mm² footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

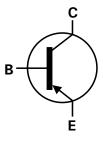
Mechanical Data

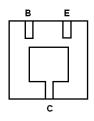
- Case: DFN2020B-3
- Case material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal package height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

Applications

- MOSFET Gate Driving
- DC-DC Converters
- Charging Circuits
- Power switches
- Motor control







Device Symbol

Bottom View Pin-Out

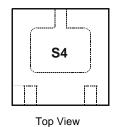
Ordering Information

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP722MATA	S4	7	8	3000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com

Marking Information



S4 = Product Type Marking code





Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Collector-Base Voltage		V _{CBO}	-70		
Collector-Emitter Voltage		V _{CEO}	-70	V	
Emitter-Base Voltage		V _{EBO}	-7		
Peak Pulse Current		I _{CM}	-3		
Continuous Collector Current	(Note 3)	1-	-2.5		
Continuous Collector Current	(Note 4)	IC	-2.7] ^	
Base Current		I _B	-1		

Thermal Characteristics @T_A = 25°C unless otherwise specified

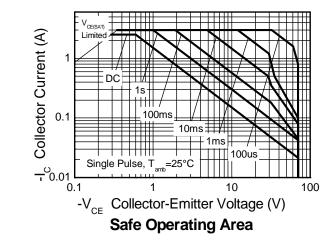
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 3)		1.5 12	w	
Linear Derating Factor	(Note 4)	P _D	2.45 19.6	mW/°C	
Thermal Decistores Junction to Ambient	(Note 3)	-	83		
Thermal Resistance, Junction to Ambient	(Note 4)	R _θ JA	51	°C/W	
Thermal Resistance, Junction to Lead (Note 5)		$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

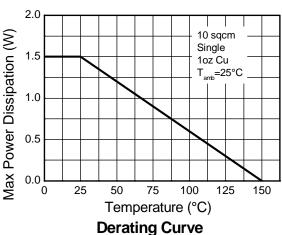
- 3. For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
- 4. Same as note (3), except the device is measured at t ≤ 5 sec.

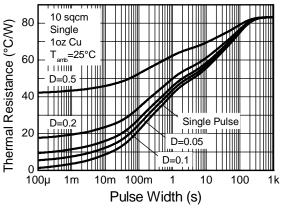
 5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

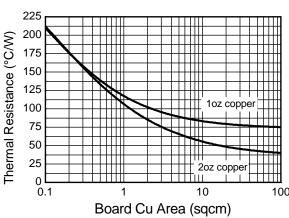


Thermal Characteristics









Transient Thermal Impedance

3.5
3.0
T_{arrb}=25°C
2.5
Continuous
2.0
Continuous
1.5
1.0
0.5
0.0
0.1
1
10
100

Thermal Resistance v Board Area

Power Dissipation v Board Area

Board Cu Area (sqcm)





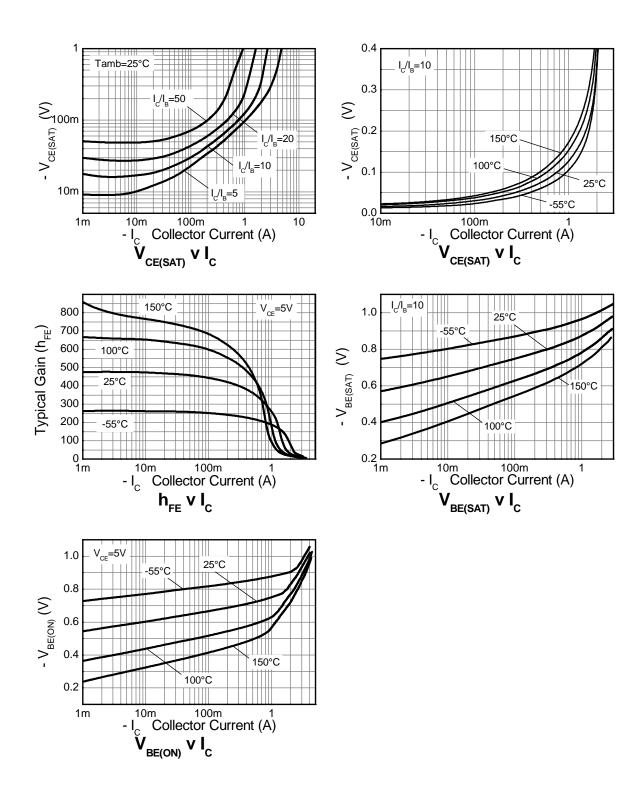
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-70	-150	-	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	-70	-125	-	V	$I_C = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.5	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	I _{CBO}	-	-	-100	nA	$V_{CB} = -55V$
Emitter Cutoff Current	I _{EBO}	-	-	-100	. nA	$V_{EB} = -6V$
Collector Emitter Cutoff Current	I _{CES}	-	-	-100	nA	V _{CES} = -55V
Static Forward Current Transfer Ratio (Note 6)	h _{FE}	300 300 175 40	470 450 275 60 10	- - - -	-	$\begin{split} &I_{C} = -10\text{mA}, \ V_{CE} = -5\text{V} \\ &I_{C} = -100\text{mA}, \ V_{CE} = -5\text{V} \\ &I_{C} = -1\text{A}, \ V_{CE} = -5\text{V} \\ &I_{C} = -1.5\text{A}, \ V_{CE} = -5\text{V} \\ &I_{C} = -3\text{A}, \ V_{CE} = -5\text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}		-35 -135 -140 -175	-50 -200 -220 -270	mV	$I_C = -0.1A$, $I_B = -10mA$ $I_C = -0.5A$, $I_B = -20mA$ $I_C = -1A$, $I_B = -100mA$ $I_C = -1.5A$, $I_B = -200mA$
Base-Emitter Turn-On Voltage (Note 6)	V _{BE(on)}	-	-0.78	-1.00	V	$I_C = -1.5A$, $V_{CE} = -5V$
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	-	-0.94	-1.05	V	$I_C = -1.5A$, $I_B = -200mA$
Output Capacitance	C_obo	-	14	20	pF	$V_{CB} = -10V. f = 1MHz$
Transition Frequency	f _T	150	180	-	MHz	$V_{CE} = -10V, I_{C} = -50mA,$ f = 100MHz
Turn-On Time	t _{on}	-	40	-	ns	$V_{CC} = -50V, I_{C} = -1A$
Turn-Off Time	t _{off}	-	700	-	ns	$I_{B1} = I_{B2} = -50 \text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

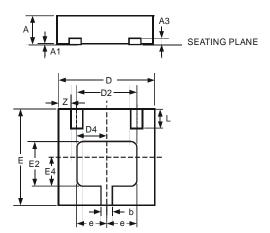


Typical Electrical Characteristics



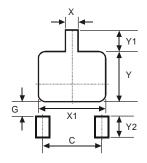


Package Outline Dimensions



DFN2020B-3						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0	0.05	0.02			
A3		_	0.152			
b	0.20	0.30	0.25			
D	1.95	2.075	2.00			
D2	1.22	1.42	1.32			
D4	0.56	0.76	0.66			
е		_	0.65			
Е	1.95	2.075	2.00			
E2	0.79	0.99	0.89			
E4	0.48	0.68	0.58			
L	0.25	0.35	0.30			
Z		_	0.225			
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)			
С	1.30			
G	0.24			
Х	0.35			
X1	1.52			
Υ	1.09			
Y1	0.47			
Y2	0.50			





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